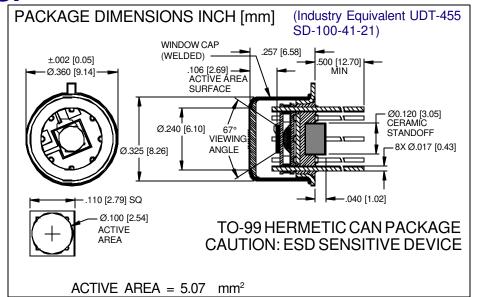
PHOTONIC DETECTORS INC.

Detector Amplifier Hybrid, Blue Enhanced Type PDB-706





RESPONSIVITY (A/W)

FEATURES

- Low input bias current
- Low offset voltage
- 1 MHz bandwidth

DESCRIPTION

The **PDB-706** is a low noise, medium speed, blue enhanced silicon photodiode integrated with a low noise JFET monolithic transimpedance op-amp. The feedback capacitor & resistor circuit are externally connected.

APPLICATIONS

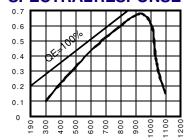
- Medical diagnostic
- Low signal level applications
- Spectroscopy

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS
V BR	Reverse Voltage		15	V
T _{STG}	Storage Temperature	-55	+125	∞
То	Operating Temperature Range	0	+70	∘C
Ts	Soldering Temperature*		+240	∘C
I _L	Light Current		500	mA

^{*1/16} inch from case for 3 secs max

SPECTRAL RESPONSE



WAVELENGTH(nm)

PHOTODIODE ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Isc	Short Circuit Current	H = 100 fc, 2850 K	45	65		μA
ΙD	Dark Current	$H = 0, V_R = 10 V$		1.0	5.0	nA
RsH	Shunt Resistance	$H = 0, V_R = 10 \text{ mV}$.5	2		GΩ
TC Rsh	RSH Temp. Coefficient	$H = 0, V_R = 10 \text{ mV}$		-8		%/°C
CJ	Junction Capacitance	$H = 0, V_R = 10 V^{**}$		15		рF
λrange	Spectral Application Range	Spot Scan	350		1100	nm
λр	Spectral Response - Peak	Spot Scan		950		nm
VBR	Breakdown Voltage	I = 10 μμΑ	100	125		V
NEP	Noise Equivalent Power	VR = 10 V @ Peak		2.5x10 ⁻¹⁴		W/ √ Hz
tr	Response Time	$RL = 1 K\Omega V_R = 10 V$		15		nS

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Detector Amplifier Hybrid, Blue Enhanced Type PDB-706

AMPLIFIER SPECIFICATION TA = 25° C and VS = ± 15 vdc UNLESS OTHERWISE NOTED

CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS
FEEDBACK NETWORK EXTERNAL		-	-	-	Ω
V _{IO} INPUT OFFSET VOLTAGE	INITIAL OFFSET FULL RANGE		0.6	3.9	mV
VIO IN OT OTT OLI VOLIAGE	LONGTERMOFFSETSTABILITY		.04		μV/MONTH
I _B INPUT BIAS CURRENT	OFFSET CURRENT, VCM=0		4		рА
R _i INPUT RESISTANCE	DIFFERENTIAL		1 X 10 ⁻¹²		
	COMMONMODE		1 X 10 ⁻¹²		Ω
	COMMONMODE	-12	+16		V
V _{ICR} INPUT VOLTAGE RANGE	COMMONMODE REJECTION VCM±10 V	72	90		
	VOLTAGE 0, f=1 KHz		2		μV_{PP}
V _{N(PP)} INPUT VOLTAGE NOISE	VOLTAGE 0, f=10 KHz		40		nV∕√Hz
I _N INPUT CURRENT NOISE	f=1 KHz		1		fA / √Hz
B _{OM} FREQUENCY RESPONSE	UNITY GAIN, SMALL SIGNAL $R_L = 10 \text{ K}\Omega$ $C_L = 100 \text{ pF}$		2		MHz
	SLEW RATE, UNITY GAIN	2.6	3.4		V/µs
A _{VD} OPEN LOOP GAIN	vo= \pm 10 V, R _L =10 KΩ	20	230		V/mV
V _{OM+} OUTPUT CHARACTERISTICS	VOLTAGE @ R _L =10 KΩ	±13.2	±13.7		V
OM±OOTI OT OTIALIAOTELIIOTIOO	VOLTAGE @ R_L = 600 Ω	±12.5	±13		V
V _{CC±} POWER SUPPLY	OPERATING RANGE	±3.5	±15	±18	V

AMPLIFIER ABSOLUTE MAXIMUM BATING (TA=25°C LINLESS OTHERWISE NOTED)

PARAMETER	MIN	MAX	UNITS
SUPPLYVOLTAGE	±4.5	±18	V
INTERNAL POWER DISSIPATION		500	mW
STORAGETEMPERATURE	-55	+150	°C
OPERATINGTEMPERATURE	0	+70	° C

WARNING: ESD SENSITIVE DEVICE PHOTOVOLTAIC

PIN CONNECTIONS

- PIN CONNECTIONS

 1. OFFSET ADJUSTMENT

 2. INVERTING INPUT, CATHODE OF PHOTODIODE

 3. NON-INVERTING INPUT, CASE GROUND

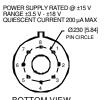
 4. NEGATIVE SUPPLY VOLTAGE

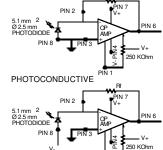
 5. OFFSET ADJUSTMENT

 6. OUTPUT

 7. POSITIVE SUPPLY VOLTAGE

 8. ANODE OF PHOTODIODE





BOTTOM VIEW